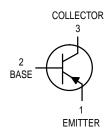
Amplifier Transistor PNP Silicon



MAXIMUM RATINGS

| Rating | Symbol | Value | Unit |
|---|-----------------------------------|-------------|----------------|
| Collector-Emitter Voltage | VCEO | -100 | Vdc |
| Collector-Base Voltage | Vсво | -100 | Vdc |
| Emitter-Base Voltage | V _{EBO} | -4.0 | Vdc |
| Collector Current — Continuous | IC | -600 | mAdc |
| Total Device Dissipation @ T _A = 25°C Derate above 25°C | PD | 625 5.0 | mW mW/°C |
| Total Device Dissipation @ T _C = 25°C Derate above 25°C | PD | 1.5 12 | Watts mW/°C |
| Operating and Storage Junction Temperature Range | T _J , T _{stg} | -55 to +150 | °C |

THERMAL CHARACTERISTICS

| Characteristic | Symbol | Max | Unit |
|---|----------------|------|------|
| Thermal Resistance, Junction to Ambient | $R_{	heta JA}$ | 200 | °C/W |
| Thermal Resistance, Junction to Case | $R_{	heta JC}$ | 83.3 | °C/W |

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

| Characteristic | Symbol | Min | Max | Unit |
|---|------------------|------|------|------|
| OFF CHARACTERISTICS | | | | |
| Collector-Emitter Breakdown Voltage ⁽¹⁾ (I _C = -1.0 mAdc, I _B = 0) | V(BR)CEO | -100 | _ | Vdc |
| Collector–Base Breakdown Voltage (I _C = –100 μAdc, I _E = 0) | V(BR)CBO | -100 | _ | Vdc |
| Emitter-Base Breakdown Voltage ($I_E = -10 \mu Adc, I_C = 0$) | V(BR)EBO | -4.0 | _ | Vdc |
| Collector Cutoff Current (V _{CB} = -50 Vdc, I _E = 0) | ІСВО | _ | -1.0 | μAdc |
| Emitter Cutoff Current (VEB = -3.0 Vdc, IC = 0) | I _{EBO} | _ | -100 | nAdc |

^{1.} Pulse Test: Pulse Width = 300 μ s, Duty Cycle = 2.0%.

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ELECTRICAL CHARACTERISTICS ($T_A = 25$ °C unless otherwise noted) (Continued)

| Characteristic | Symbol | Min | Max | Unit |
|--|------------------|--------|----------------|------|
| ON CHARACTERISTICS ⁽¹⁾ | | | • | |
| DC Current Gain ⁽¹⁾ (I _C = -50 mAdc, V _{CE} = -5.0 Vdc) | h _{FE} | 40 | 250 | _ |
| Collector-Emitter Saturation Voltage (I _C = -10 mAdc, I _B = -1.0 mAdc) (I _C = -50 mAdc, I _B = -5.0 mAdc) | VCE(sat) | _ | -0.25 -0.30 | Vdc |
| Base-Emitter Saturation Voltage (I _C = -10 mAdc, I _B = -1.0 mAdc) (I _C = -50 mAdc, I _B = -5.0 mAdc) | VBE(sat) | _ _ | -1.2 -1.2 | Vdc |
| SMALL-SIGNAL CHARACTERISTICS | | | | |
| Current-Gain — Bandwidth Product (I _C = -10 mAdc, V _{CE} = -10 Vdc, f = 20 MHz) | fŢ | 60 | _ | MHz |
| Output Capacitance (V _{CB} = -10 Vdc, I _E = 0, f = 1.0 MHz) | C _{obo} | _ | 8.0 | pF |
| Small–Signal Current Gain ($I_C = -1.0 \text{ mAdc}$, $V_{CE} = -10 \text{ Vdc}$, $f = 1.0 \text{ kHz}$) | h _{fe} | 20 | _ | _ |

^{1.} Pulse Test: Pulse Width = 300 μs, Duty Cycle = 2.0%.

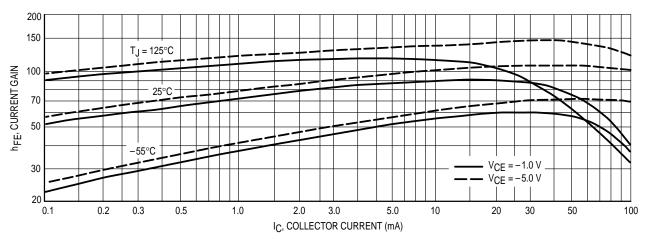


Figure 1. DC Current Gain

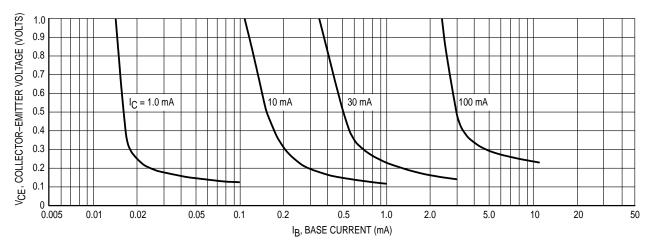


Figure 2. Collector Saturation Region

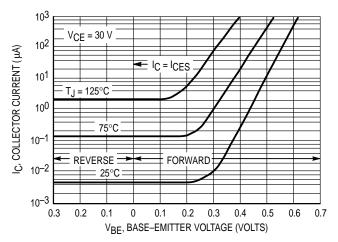


Figure 3. Collector Cut-Off Region

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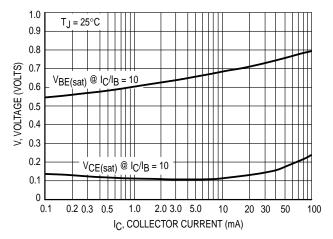


Figure 4. "On" Voltages

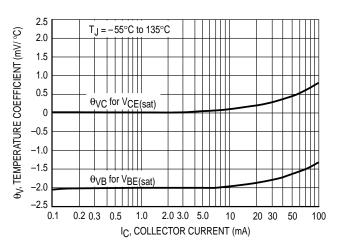
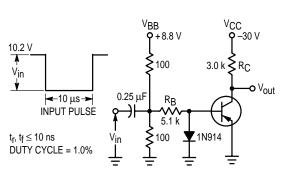


Figure 5. Temperature Coefficients



Values Shown are for I_C @ 10 mA

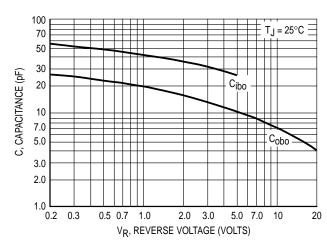
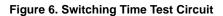


Figure 7. Capacitances



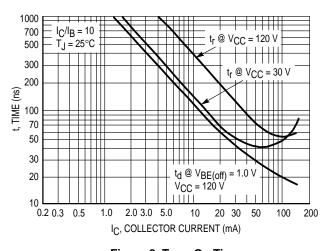


Figure 8. Turn-On Time

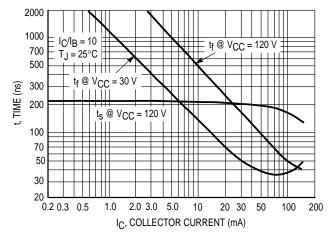
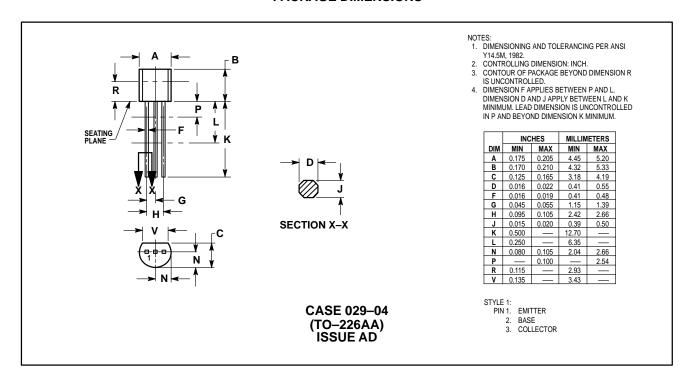


Figure 9. Turn-Off Time

PACKAGE DIMENSIONS



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